

# 6MBI100U2B-060

IGBT Modules

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## IGBT MODULE (U series) 600V / 100A



### ■ Features

- Low  $V_{CE(sat)}$
- Compact Package
- P.C. Board Mount Module

### ■ Applications

- Inverter for Motoe Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply

### ■ Maximum ratings and characteristics

● Absolute maximum ratings ( $T_c=25^{\circ}\text{C}$  unless otherwise specified)

Item	Symbol	Condition	Rating	Unit	
Collector-Emitter voltage	$V_{CES}$		600	V	
Gate-Emitter voltage	$V_{GES}$		$\pm 20$	V	
Collector current	$I_c$	Continuous	100	A	
	$I_{cP}$	1ms	200		
	$-I_c$		100		
	$-I_c$ pulse		200		
Collector power dissipation	$P_c$	1 device	380	W	
Operating junction temperature	$T_j$		+150	$^{\circ}\text{C}$	
Storage temperature	$T_{stg}$		-40 to +125	$^{\circ}\text{C}$	
Isolation voltage	$V_{iso}$	AC : 1 minute	between terminal and copper base *2	AC 2500	V
			between thermistor and others *3	AC 2500	V
Mounting screw torque			3.5 *1	N·m	

\*1 Recommendable value : 2.5 to 3.5 N·m (M5)

\*2 All terminals should be connected together when isolation test will be done.

\*3 Two thermistor terminals should be connected together, each other terminals should be connected together and shorted to base plate when isolation test will be done.

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## ● Electrical characteristics (Tj=25°C unless otherwise specified)

Item	Symbol	Condition	Characteristics			Unit	
			Min.	Typ.	Max.		
Zero gate voltage collector current	ICES	VCE=600V, VGE=0V	-	-	1.0	mA	
Gate-Emitter leakage current	IGES	VCE=0V, VGE=±20V	-	-	200	nA	
Gate-Emitter threshold voltage	VGE(th)	VCE=20V, Ic=100mA	6.2	6.7	7.7	V	
Collector-Emitter saturation voltage	VCE(sat) (terminal)	VGE=15V Ic=100A	Tj=25°C	-	2.20	2.50	V
			Tj=125°C	-	2.35	-	
	VCE(sat) (chip)	Tj=25°C	-	1.85	-		
		Tj=125°C	-	2.00	-		
Input capacitance	Cies	VGE=0V, VCE=10V, f=1MHz	-	8.4	-	nF	
Turn-on time	ton	VCC=300V	-	0.40	1.20	µs	
	tr	Ic=100A	-	0.22	0.60		
	tr(i)	VGE=±15V	-	0.16	-		
	toff	RG= 33 Ω	-	0.48	1.20		
Turn-off time	tr		-	0.07	0.45		
Forward on voltage	VF (terminal)	VGE= 0 V IF=100A	Tj=25°C	-	1.95	2.30	V
			Tj=125°C	-	2.00	-	
	VF (chip)	Tj=25°C	-	1.60	-		
		Tj=125°C	-	1.65	-		
Reverse recovery time	trr	IF=100A	-	-	0.35	µs	
Lead resistance, terminal-chip *	R lead		-	3.4	-	mΩ	
Thermistor	Resistance	T=25°C	-	5000	-	Ω	
		T=100°C	465	495	520		
	B value	B	T=25/50°C	3305	3375	3450	K

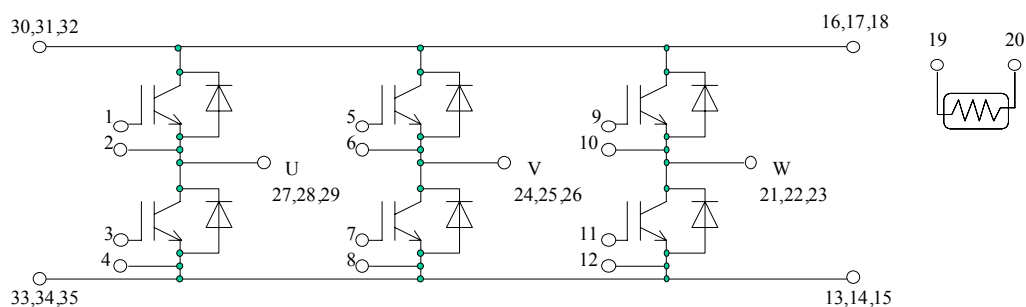
\* Biggest internal terminal resistance among arm.

## ● Thermal resistance Characteristics

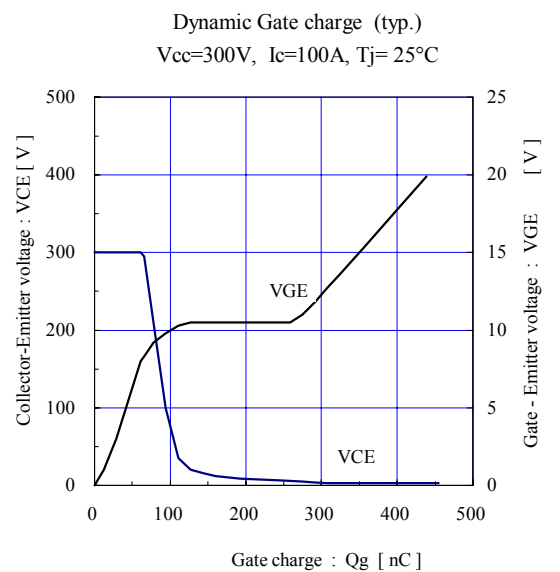
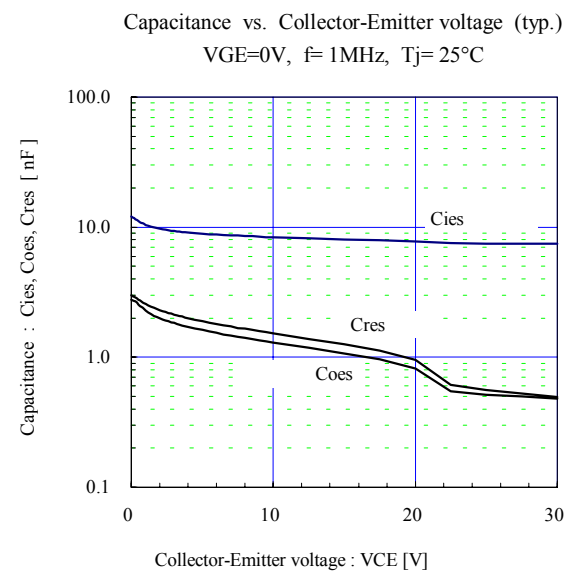
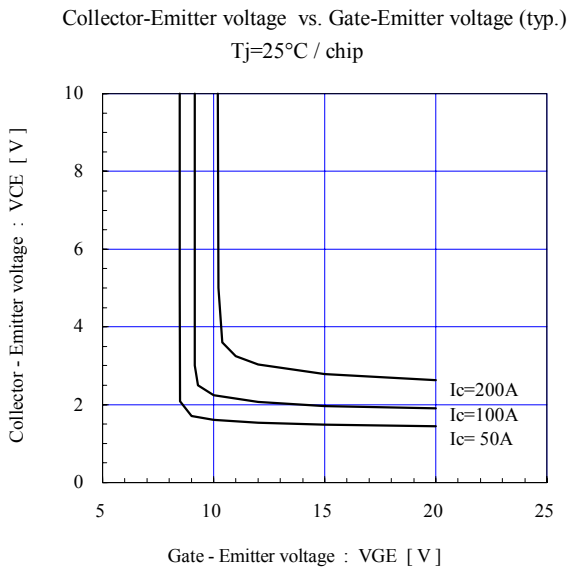
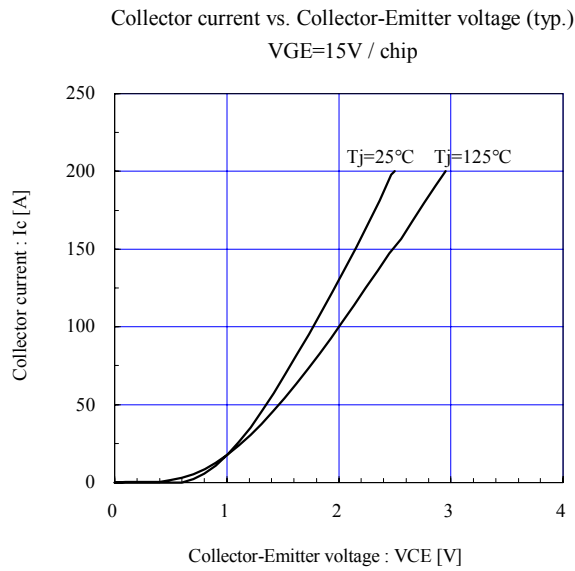
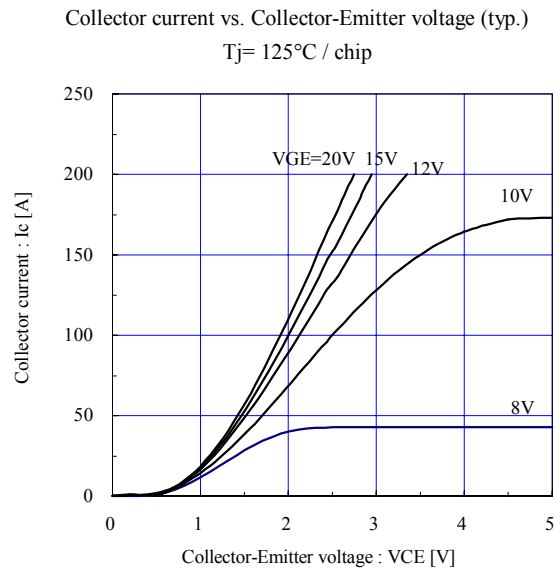
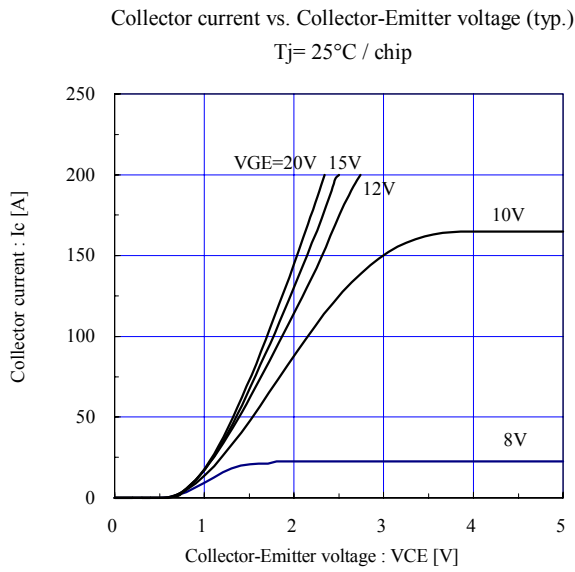
Item	Symbol	Condition	Characteristics			Unit
			Min.	Typ.	Max.	
Thermal resistance ( 1 device )	Rth(j-c)	IGBT	-	-	0.33	°C/W
		FWD	-	-	0.66	
Contact thermal resistance *	Rth(c-f)	With thermal compound	-	0.05	-	

\* This is the value which is defined mounting on the additional cooling fin with thermal compound

## ■ Equivalent Circuit Schematic

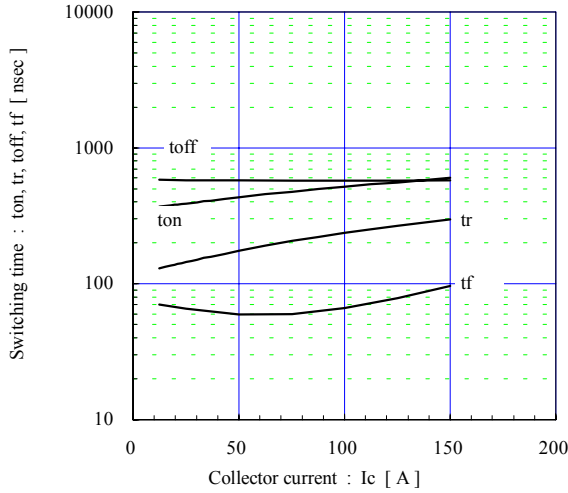


■ Characteristics (Representative)

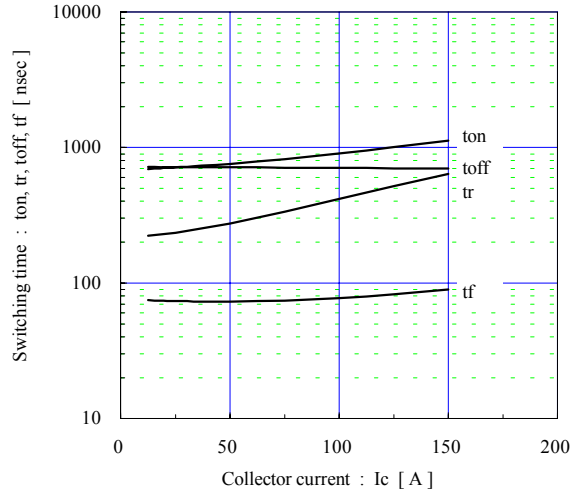


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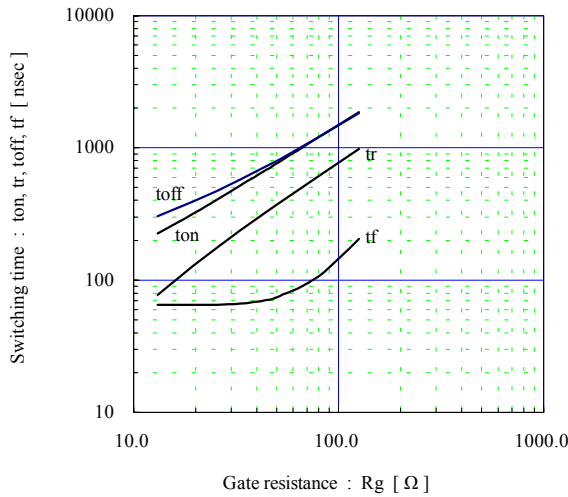
Switching time vs. Collector current (typ.)  
 $V_{cc}=300V, V_{GE}=\pm 15V, R_g=33\Omega, T_j=25^\circ C$



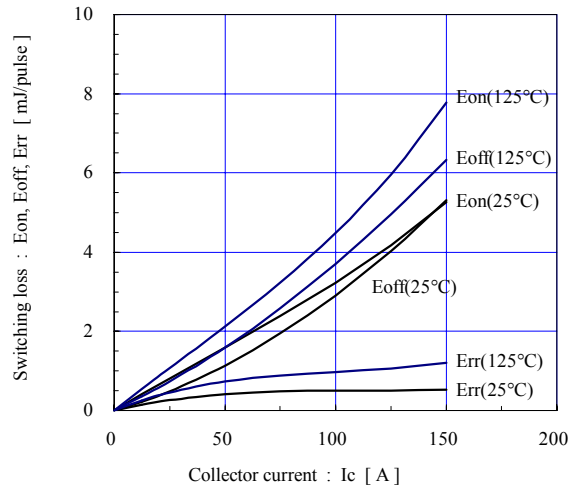
Switching time vs. Collector current (typ.)  
 $V_{cc}=300V, V_{GE}=\pm 15V, R_g=33\Omega, T_j=125^\circ C$



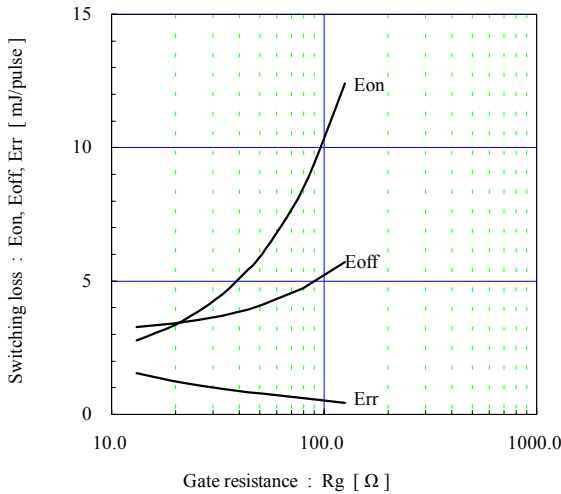
Switching time vs. Gate resistance (typ.)  
 $V_{cc}=300V, I_c=100A, V_{GE}=\pm 15V, T_j=25^\circ C$



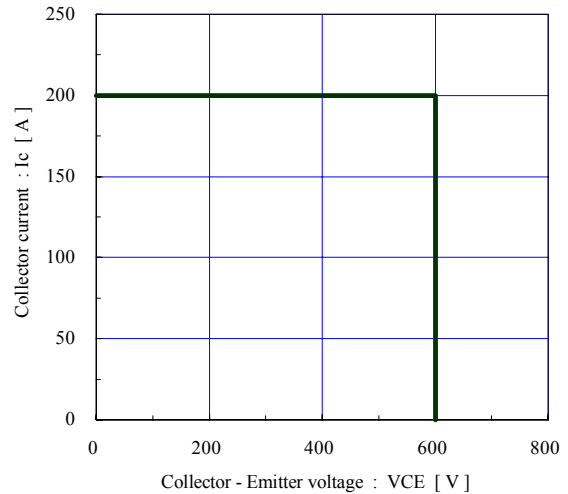
Switching loss vs. Collector current (typ.)  
 $V_{cc}=300V, V_{GE}=\pm 15V, R_g=33\Omega$



Switching loss vs. Gate resistance (typ.)  
 $V_{cc}=300V, I_c=100A, V_{GE}=\pm 15V, T_j=125^\circ C$

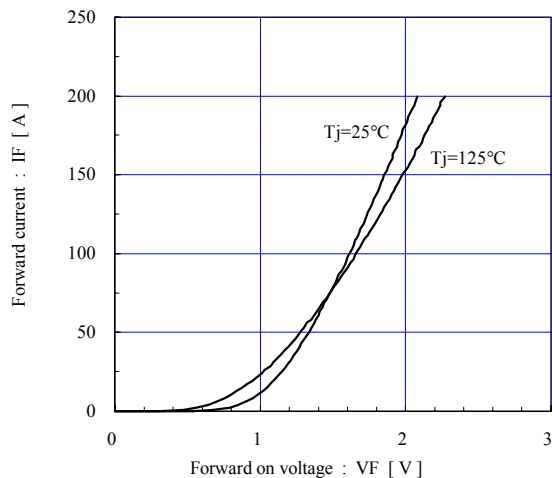


Reverse bias safe operating area (max.)  
 $+V_{GE}=15V, -V_{GE} \le 15V, R_g \ge 33\Omega, T_j \le 125^\circ C$

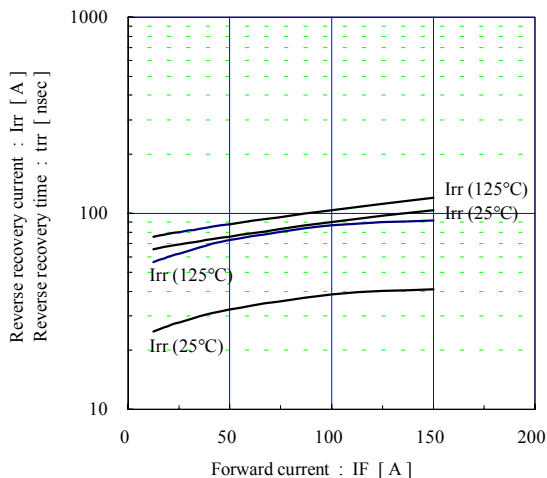


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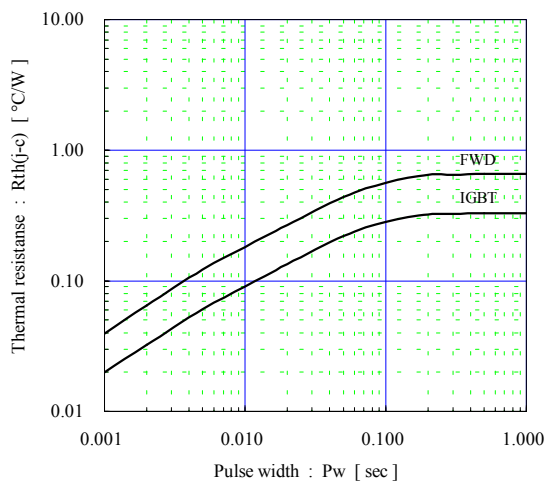
Forward current vs. Forward on voltage (typ.)  
chip



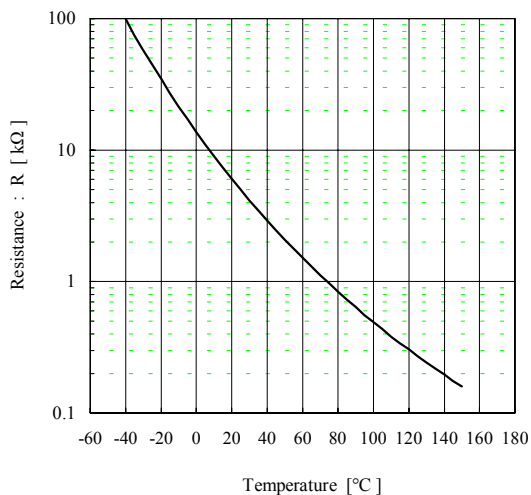
Reverse recovery characteristics (typ.)  
 $V_{cc}=300\text{V}$ ,  $V_{GE}=\pm 15\text{V}$ ,  $R_g=33\Omega$



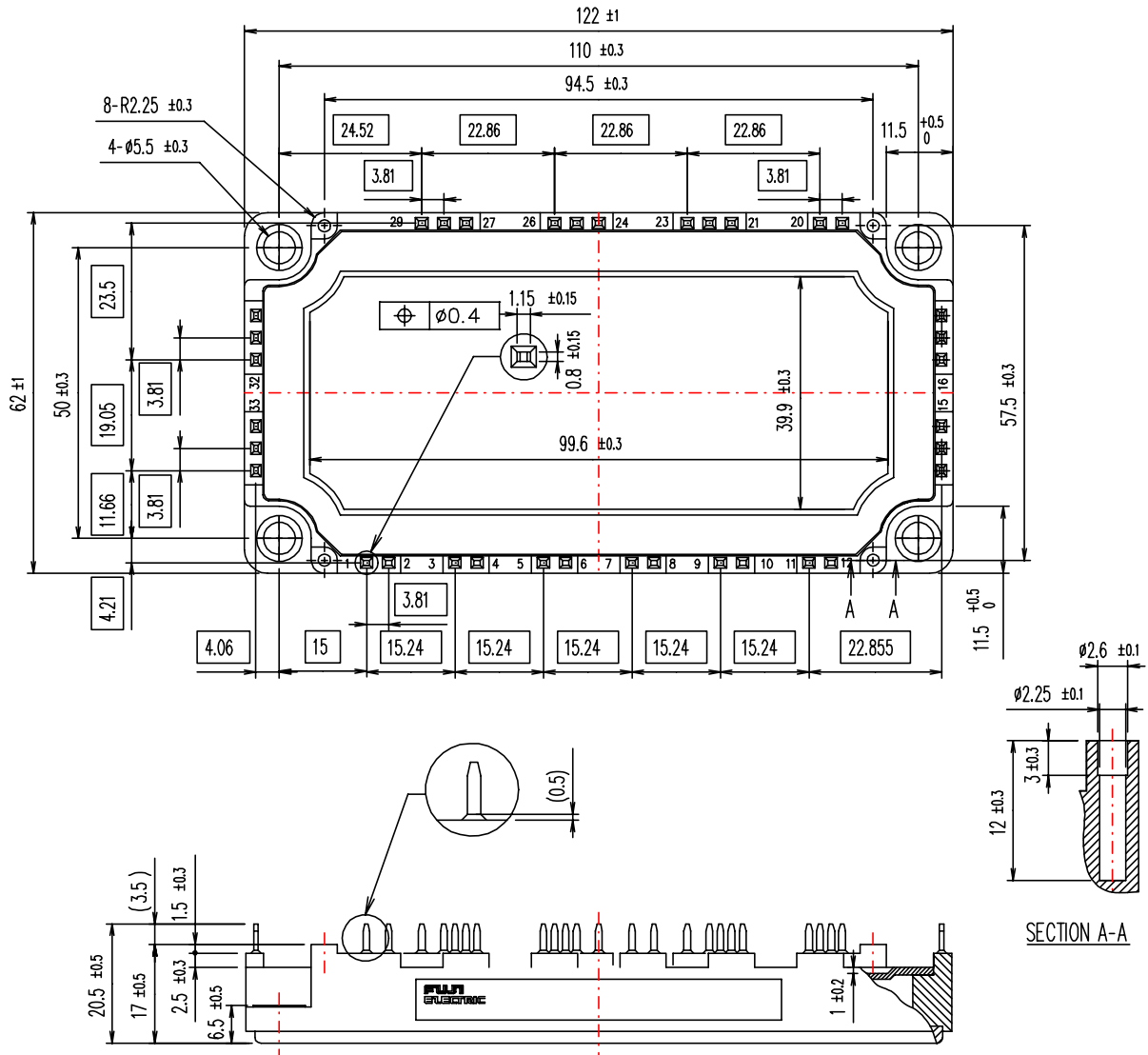
Transient thermal resistance (max.)



Temperature characteristic (typ.)



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■ Outline Drawings, mm



□ shows theoretical dimension.  
( ) shows reference dimension.